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Pan, H.J.; Lin, K.W.; Yu, K.H.; Cheng, C.C.; Thej, K.B.; Liu, W.C.; Chen, H.I.

Electronics Letters, Volume: 38 Issue: 2, 17 Jan. 2002

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2 Monolithic InGaAsP optoelectronic devices with silicon electronics

Fehly, D.; Schlachetzki, A.; Bakin, A.S.; Guttzeit, A.; Wehmann, H.-H.

Quantum Electronics, IEEE Journal of, Volume: 37 Issue: 10, Oct. 2001

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3 Numerical simulation of field effect transistors in 4H and 6H-SiC

Nilsson, H.E.; Bertilsson, K.; Dubaric, E.; Hjelm, M.

Wide Bandgap Layers, 2001. Abstract Book. 3rd International Conference on Novel Applications of, 2001

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[\[Abstract\]](#) [\[PDF Full-Text \(81 KB\)\]](#) **CNF**

4 High quality ultra-thin (2.4 nm) oxide prepared by clustered vertical furnace with in-situ HF-vapor pre-gate oxide cleaning

Chao, T.S.; Chen, J.L.; Lai, C.S.; Lin, H.C.; Huang, T.Y.

VLSI Technology, Systems, and Applications, 1999. International Symposium on, 1999

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